

IN 5832

SCHOTTKY RECTIFIER



NAINA



Designer's Data Sheet Switchmode Power Rectifiers

employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlap contact. Ideally suited for use as rectifiers in low-voltage, high-frequency inverters, free wheeling diodes, and polarity protection diodes.

- Extremely Low V_F
- Low Stored Charge, Majority Carrier Conduction
- Low Power Loss/High Efficiency
- High Surge Capacity

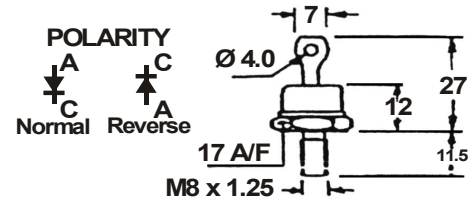
Mechanical Characteristics :

- Case Welded steel, hermetically sealed
- Finish : All External Surfaces Corrosion Resistant and Terminal Lead is Readily Solderable

Solder Heat : The excellent heat transfer property of the heavy duty copper anode terminal which transmits heat away from the die requires that caution be used when attaching wires.

- Stud Torque: 15 lb-in max

40 AMPERE
20 VOLTS



MAXIMUM RATINGS

Ratings	Symbol	1N5832	UNIT
Peak Repetitive Reverse Voltage	V_{RRM}	20	Volts
Working Peak Reverse Voltage	V_{RWM}		
PC Blocking Voltage	V_{RSM}		
Nonrepetitive Peak Reverse Voltage	V_{RSM}	24	Volts
Average Rectified Forward Current $V_{R(equiv)} \leq 0.2 V_{R(dc)}, T_C=85^\circ C$	I_o	40	Amps
Ambient Temperature Rated $V_{R(dc)}, P_{F(AV)}=0, R_{\theta JA}=3.5^\circ C/W$	T_A	100	$^\circ C$
Nonrepetitive Peak Surge Current (surge applied at rated load conditions, halfwave, single phase, 50 Hz)	I_{FSM}	800 for one cycle	Amps
Operating and Storage Junction Temperature Range (Reverse voltage applied)	T_J, T_{stg}	-65 to + 125	$^\circ C$
Peak Operating Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	150	$^\circ C$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction to case	$R_{\theta JC}$	1.0	$^\circ C/W$

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ C$ unless otherwise noted)

Maximum Instantaneous Forward Voltage ⁽¹⁾ ($I_F=10$ Amps)	V_F	0.36	Volts
($I_F=40$ Amps))		0.52	
($I_F=125$ Amps)		0.980	
Maximum Instantaneous Reverse Current @ Rated dc Voltage ⁽¹⁾ (1) ($T_C=100^\circ C$)		20	ma
		150	

Data (1) Pulse Test: Pulse Width = 300 μs , Duty Cycle=2%,